

Facile partly templating growth of Bi₂S₃ nanorods by in-situ thermal sulphuration of BiOCl nanosheets and the photosensitive properties

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Bi₂S₃ nanorods were prepared by a facile in-situ thermal sulphuration method using BiOCl nanosheets as precursors. The products were characterised by X-ray diffraction, Raman scattering, Fourier-transform infrared spectroscopy and scanning electron microscopy. The optical properties were measured by ultraviolet-visible spectroscopy and photoluminescence techniques. The photosensitive properties were investigated by the photoelectrochemical method. The Bi₂S₃ sample was of pure orthorhombic phase and composed of nanorods with average diameter of ~200 nm and length of ~2 μm. A plausible gas phase growth mechanism was proposed which involved the partly templating of the shape of precursors by transforming BiOCl nanosheets to Bi₂S₃ nanorods. The photocurrent of the products under irradiation of solar simulator reached 1.0 μA/cm² without bias voltage which was ten times that of the dark current. The photoelectric measurements clearly demonstrate that the as-prepared Bi₂S₃ nanorods possess excellent photosensitivity with stability and reproducibility, enabling the products suitable for the fabrication of high-performance photodetectors and other optoelectric devices.

1. Introduction: Bi₂S₃ belongs to an important category of A₂B₃^{VI} (A = As, Sb, Bi; B = S, Se, Te) semiconductors and is composed of low-cost earth abundant non-toxic elements [1, 2]. Bi₂S₃ nanomaterials are in particular of interest due to their attractive thermoelectric, photoelectric and photocatalytic applications [3]. As one-dimensional nanomaterials can efficiently transport charge carriers while maintaining confinement across the diameter [4, 5], Bi₂S₃ nanorods exhibit significant capabilities acting as building blocks for advanced micro-nano devices such as photodetectors, chemical sensors, solar cells and supercapacitors [6–10].

Many approaches have been used to prepare Bi₂S₃ nanorods mainly including liquid phase methods. Xue *et al.* [11] prepared Bi₂S₃ nanorods through gelatin-assisted solution process under microwave irradiation; Helal *et al.* [12] synthesised Bi₂S₃ nanorods by hydrothermal method using Bi(NO₃)₃·5H₂O and thiourea as sources. Yu *et al.* [13] used colloidal chemistry method to produce Bi₂S₃ nanorods in the mixed solution of organic amines. Nevertheless, to the best of our knowledge, there are few reports on the preparation of Bi₂S₃ nanorods by gas phase method. The facile and low-cost fabrication routes of Bi₂S₃ nanorods are still needed to be developed.

Herein we report that Bi₂S₃ nanorods can be readily produced by an in-situ thermal sulphuration of BiOCl nanosheets in a vacuum tube furnace. The composition and morphology of the samples were characterised and the evolution mechanism of the gas phase synthetic process was investigated. The optical properties were examined including their light absorption properties and photoluminescence (PL) properties. A photodetecting device was constructed to evaluate the photosensitive properties of the as-prepared Bi₂S₃ nanorods by the photoelectrochemical method.

2. Experimental section: All the reagents are of analytical grade and were used without further purification. The precursing BiOCl nanosheets were prepared according to our previous report [14]. The synthesis of Bi₂S₃ nanorods was described as follows. Typically, 0.15 g BiOCl nanosheets and 0.15 g sulphur powder were put into a crucible and placed into the vacuum tube furnace, respectively. The temperature was elevated to 350°C at a rate of 5°C/min. The furnace was maintained at 350°C for 90 min. After

that, it was allowed to cool to room temperature naturally and the products were collected for use.

X-ray diffraction (XRD) patterns were collected from a Bruker D8 Advance diffractometer with Cu Kα radiation at 1.54 Å. Raman spectrum was recorded on a Renishaw inVia spectrometer with a laser wavelength of 514 nm and Fourier-transform infrared (FTIR) spectrum was obtained from a Nicolet 6700 spectroscopy. The morphology observations were performed on a FEI Nova NanoSEM 450 microscopy. The optical properties were measured using a Cary 5000 UV-Vis-NIR spectroscopy and a Hitachi F-4600 fluorescence spectrophotometer (PL).

A photodetecting device was constructed to evaluate the photosensitive properties of the samples. Typically, a dimethylformamide dispersion of Bi₂S₃ nanorods was drop-cast on a 1 cm² Fluorine-doped Tin Oxide (SnO₂:F) (FTO) glass substrate and a Cu wire was connected to one of its edges using Ag slurry. The edges were sealed with epoxy resin to limit the direction of current during the photoelectrochemical test. A sun simulator (~100 mW/cm²) was used as the light source. Current-time (*I-t*) and current-voltage (*C-V*) curves were recorded through a two-probe method on a CHI 660B electrochemical station. The electrolyte was composed of 0.5 M Na₂SO₄ solution and the counter electrode was a Pt coil.

3. Results and discussion: The crystal phases of the samples were characterised by XRD method. Fig. 1a shows the XRD patterns of BiOCl nanosheets and the samples sulphured for different times. As seen in the figure, the precursing BiOCl nanosheets were in accordance with JCPDS Card No. 850861. After thermal sulphuration for 1 min, there appeared new weak diffraction peaks at 28.6°, 25.1°, 32.0° and 22.4°, respectively. When the sulphuration time was 10 min, the diffraction intensity of above peaks became higher and more new diffraction peaks were present; almost all of the diffraction peaks of BiOCl phase remained at this stage. While for the sulphuration time of 90 min, all the diffraction peaks in the spectrum were assigned to the orthorhombic phase of Bi₂S₃ with JCPDS Card No. 751306, indicating the BiOCl precursors were completely transformed to Bi₂S₃ phase. Moreover, there were no intermediate phases formed in the sulphuration process, suggesting the purity of the Bi₂S₃ products.

The chemical composition and chemical bonds of the samples were studied by Raman and FTIR methods. Fig. 2a is the Raman spectrum of Bi_2S_3 nanorods. There were two obvious peaks present in the spectrum, locating at 119 and 960 cm^{-1} , respectively. The peak at 119 cm^{-1} was attributed to surface optical phonon modes which were caused by the effect of interface imperfections

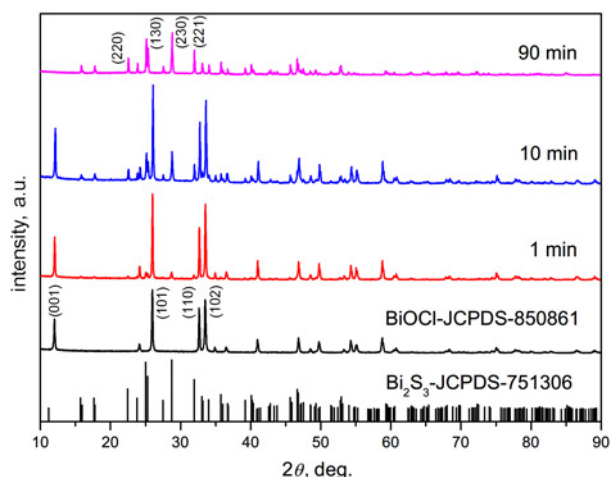


Fig. 1 XRD patterns of BiOCl nanosheets and the samples sulphured for different times

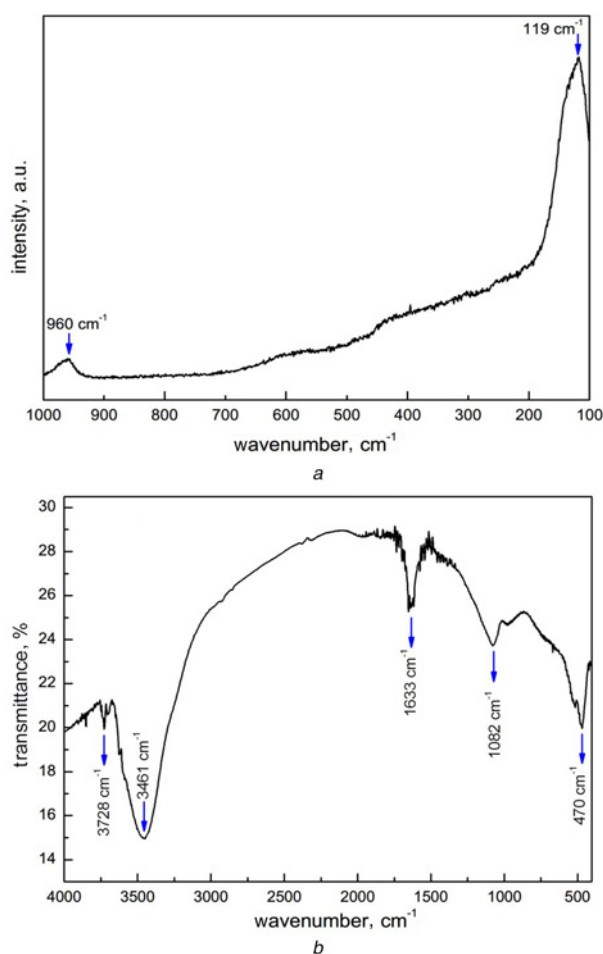


Fig. 2 Raman spectrum and FTIR spectrum of Bi_2S_3 nanorods
a Raman spectrum
b FTIR spectrum

of Bi_2S_3 nanostructures [15], while the peak at 960 cm^{-1} was assigned to Bi-S stretching vibrations [16]. The FTIR spectrum of Bi_2S_3 nanorods is displayed in Fig. 2b. There were five distinctive absorption bands in the spectrum, locating at 470, 1082, 1633, 3461 and 3728 cm^{-1} , respectively. The band at 470 cm^{-1} was attributed to Bi-S stretching vibrations and the band at 1082 cm^{-1} was corresponding to C-O stretching modes [17, 18]. The bands at 3461 and 1633 cm^{-1} were ascribed to the O-H stretching and bending modes of water; and the band at 3728 cm^{-1} could be assigned to dissociatively adsorbed water [19]. The Raman and FTIR results further confirm the formation of Bi_2S_3 phase during sulphuration process.

To reveal the formation of nanorods of Bi_2S_3 phase, scanning electron microscopy (SEM) technique was used. Fig. 3 displays the SEM images of BiOCl nanosheets and Bi_2S_3 nanorods. In Fig. 3a, BiOCl sample was composed of irregularly shaped nanosheets and the average size of BiOCl nanosheets is $\sim 2 \mu\text{m}$. The morphologies of the sulphured samples are shown in Figs. 3b–d. In Fig. 3b, there were some nanorods appearing on the surfaces of BiOCl nanosheets when the sulphuration time was 1 min. More nanorods were present and the BiOCl nanosheets disappeared gradually with prolonging the sulphuration time to 10 min, as shown in Fig. 2c. For the sulphuration time of 90 min, no BiOCl nanosheets were found shown in Fig. 2d, implying all of them were transformed to Bi_2S_3 nanorods and the average diameter of Bi_2S_3 nanorods is $\sim 200 \text{ nm}$ and the estimated average length is $\sim 2 \mu\text{m}$.

It is interesting to discuss the phase and morphology evolution mechanism of the thermal sulphuration process from BiOCl nanosheets to Bi_2S_3 nanorods. A plausible gas phase reaction related mechanism was proposed. The reaction equations are as follows and the mechanism illustration is represented in Fig. 4.

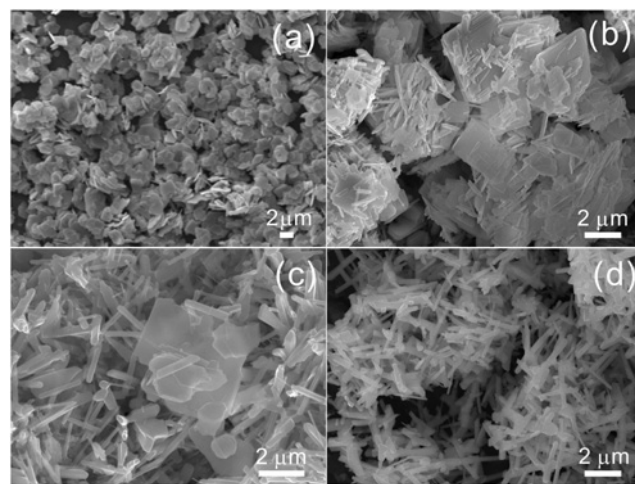


Fig. 3 SEM images of
a BiOCl nanosheets
b Samples sulphured for 1 min
c Samples sulphured for 10 min
d Samples sulphured for 90 min

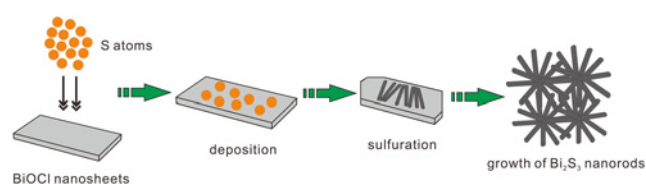


Fig. 4 Illustration of the formation mechanism of Bi_2S_3 nanorods

When the sulphur powders were heated, they sublimed and some atoms from the sulphur gas were deposited on the surfaces of BiOCl nanosheets. The BiOCl nanosheets acted not only as catalysts for the formation of Bi₂S₃ nucleus but as templates for the further growth of Bi₂S₃ nanorods. The later sulphur atoms near the interfaces of Bi₂S₃ and BiOCl continued to react with BiOCl nanosheets, making the Bi₂S₃ nucleus grow along the surfaces of BiOCl nanosheets and form randomly distributed Bi₂S₃ nanorods. It was thought that the oriented growth of Bi₂S₃ nanorods was caused by that BiOCl nanosheets were partly templated by Bi₂S₃ phase, since when sphere Bi nanoparticles were used as bismuth source in the sulphuration process, sphere Bi₂S₃ nanoparticles were obtained but not Bi₂S₃ nanorods according to our previous report [20].

The photoelectric properties are closely related to the optical properties of the samples. The light harvesting and photoluminescent behaviours were measured by ultraviolet-visible (UV-Vis) spectroscopy and PL techniques, as shown in Fig. 5. Fig. 5a is the UV-Vis spectrum of Bi₂S₃ nanorods. As seen from the figure, the Bi₂S₃ nanorods exhibited excellent light absorption capacity in the visible light range. The corresponding light absorption edge was obtained from the perpendicular to the abscissa axis from the point of intersection of the two tangent lines from the absorption spectrum [21] and the value was 937 nm with the calculated optical bandgap of 1.32 eV which agreed well with the previous report [22]. Fig. 5b is the PL spectrum of Bi₂S₃ nanorods. When the sample was excited with light of 574 nm, an intense light emission occurred at 867 nm with the photon energy of 1.43 eV, which was also observed by Yu *et al.* [23]. Obviously, there was a blue

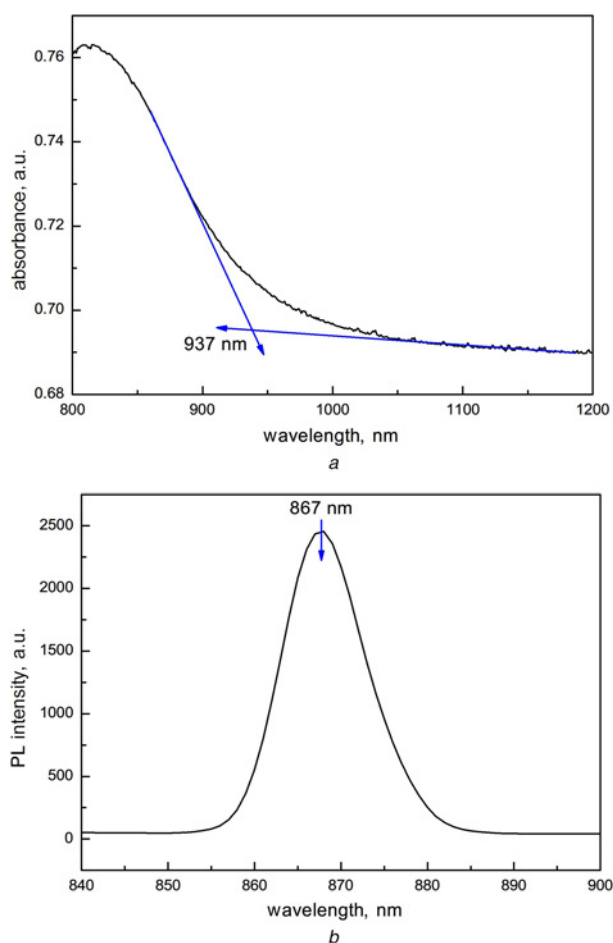


Fig. 5 UV-Vis spectrum and PL spectrum of Bi₂S₃ nanorods
a UV-Vis spectrum
b PL spectrum

shift of ~ 0.11 eV for PL compared with the measured bandgap of 1.32 eV. It could be explained by the quantum confinement effects induced by small sizes or band filling effects induced by surface defects [24].

To evaluate whether the as-prepared Bi₂S₃ nanorods could be used as photodetecting materials, the photoelectrochemical method was employed and the results are represented in Fig. 6. Fig. 6a is the current versus time (*I-t*) curve with zero bias voltage of Bi₂S₃ nanorods. In the figure, the dark current was 90 nA/cm² and the photocurrent reached 1.0 μ A/cm². It clearly indicates that the photocurrent was approximately ten times that of dark current, suggesting the sample was very photosensitive. Moreover, the light-on photocurrent and the stable photocurrent after five cycles were retained at ~ 1.0 and 0.31 μ A/cm², respectively, exhibiting the high stability and reproducibility of photosensitive properties. Fig. 6b is the current versus potential (*C-V*) curves of Bi₂S₃ nanorods. The dark current increased gradually with the elevated bias voltage varying from 90 nA/cm² to 2.2 μ A/cm²; while the photocurrent changed from 0.56 to 7.7 μ A/cm² within the same bias voltage range. The inset of Fig. 6b shows the light-on photocurrent and the stable photocurrent became higher when increasing bias voltage, giving the value of 7.7 and 6.0 μ A/cm² at the bias voltage of 0.6 V. The above results demonstrate that the as-prepared Bi₂S₃ nanorods are of highly photosensitive no matter with or without bias voltage.

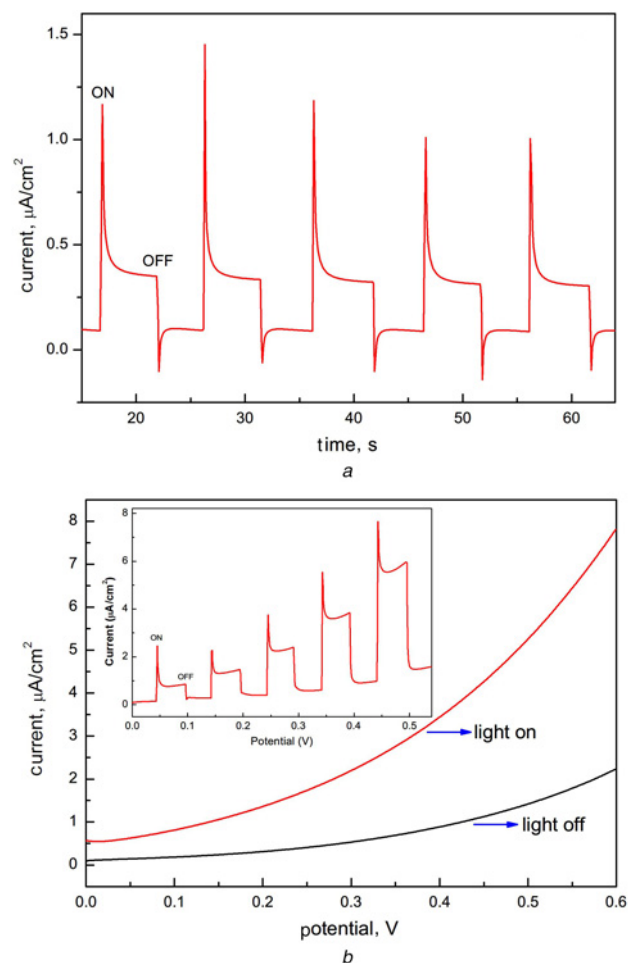


Fig. 6 Current versus time curve and current versus potential curves when the light was on and off of Bi₂S₃ nanorods
a Current versus time curve with zero bias voltage when the light was intermittently turned on and off of Bi₂S₃ nanorods
b Current versus potential curves when the light was on and off of Bi₂S₃ nanorods. Inset is current versus potential curve when the light was intermittently turned on and off of Bi₂S₃ nanorods

4. Conclusion: Bi₂S₃ nanorods were successfully prepared by a facile in-situ thermal sulphuration method using BiOCl nanosheets as precursors. The formation of Bi₂S₃ nanorods involved a gas phase reaction process during which the BiOCl nanosheets were partly templated by the oriented growth of Bi₂S₃ phase. The phase of Bi₂S₃ nanorods is pure and the mean diameter is ~200 nm and the mean length is ~2 μm. The light absorption edge is 937 nm and the PL peak is blue shifted to 867 nm. The photocurrent without bias voltage is 1.0 μA/cm² and the value reaches 7.7 μA/cm² at the bias voltage of 0.6 V. Especially, the photocurrent without bias voltage is ten times that of the dark current. Our work reported here provides a facile and cost-efficient route for large-scale production of Bi₂S₃ nanorods which could be potentially used as highly photosensitive materials for the fabrication of photodetectors or other photoelectric devices.

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6 References

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